## NSN 5961-01-041-6812

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-041-6812 **Inclosure Material:** Plastic **Overall Length:** Between 0.360 inches and 0.400 inches **Overall Height:** Between 0.170 inches and 0.190 inches **Overall Width:** Between 0.285 inches and 0.315 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** -30.0 collector to emitter voltage/static/base open and -5.0 emitter to base voltage, static, collector open and -45.0 collector to emitter voltage, dc with base short-circuited to emitter **Current Rating Per Characteristic:** 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 12.5 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No